

KERALA AGRICULTURAL UNIVERSITY

B.Tech.(Food Engg) 2018 Admission

II Semester Final Examination- June 2019

BASIC ELECTRICAL ENGINEERING (2+1)

Marks: 50 Time: 2 hours

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·T	A	Fill up the blanks	(10x1=10
1	A	Fit up the blanks	percent
	1	Energy stored by a coil is doubled when its current is increased by	percent
	2	In a series RC circuit as frequency increases current	
	2	Ill a series RC circuit as nequency metabolic	
	3	The r.m.s. value of sinusoidal 100 V peak to peak is volt	its length then it

- Resistance of a wire is r ohms. The wire is stretched to double its length, then its resistance in ohms is
- A star circuit has each element of resistance R/2. The equivalent delta elements will be 5
- The power factor of a purely resistive circuit is_____. 6
- Answer the following. B
- Define dynamically induced emf.
- Define form factor of an alternating quantity. 8
- Y=BC+AC. Draw the logic gate for this expression 9
- 10 Draw the V-I characteristics of ideal diode.

Write Short notes on any FIVE of the following II

(5x2=10)

- Derive the ripple factor of a full- wave rectifier. 1
- Kirchhoff's current law. 2
- Active and passive element with an example. 3
- An NPN transistor has collector current 4mA and base current 10 $\mu A.$ Calculate α and β values of the transistor, neglecting the reverse sat current I_{CBO}
- Convert the Boolean expression in logic gate $F = X + \overline{Y + Z} + X \cdot Y$ 5
- Mutual inductance. 6
- Define Demorgan's theorems.

Answer any FIVE of the following. III

(5x4=20)

- A three phase load consists of three similar inductive coils, each of resistance 50Ω and inductance 0.3 H. The supply is 415 V, 50Hz. Calculate (a) line current (b) power factor when the load is connected in star.
- Find the voltage across 1 and 2 using nodal analysis of the circuitas shown in Fig.1 2

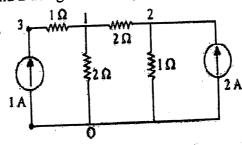
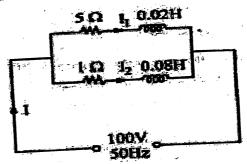


Fig.1

Solve the expression X+(Y.Z) = (X+Y).(X+Z)

Find the net impedance and total current in the parallel circuit shown below.



- An NPN transistor used for voltage divider biasing has the following parameters α= 0.985, $V_{BE} = 0.3V$, $V_{CE} = 16V$. If the operating point Q is at $I_{C} = 2mA$, $V_{CE} = 6V$, then calculate R_1 & R_C for R_2 = 20k Ω .
- CB operation of transistor.
- Difference between p type and n type semiconductors.

(1x10=10)

IV

- Answer any ONE of the following With a neat sketch, explain the working principle of half-wave rectifier and derive the expression for efficiency & output voltage
- State and explain Thevenin's theorem with circuit diagram. 2